



30V P-Channel Enhancement Mode MOSFET

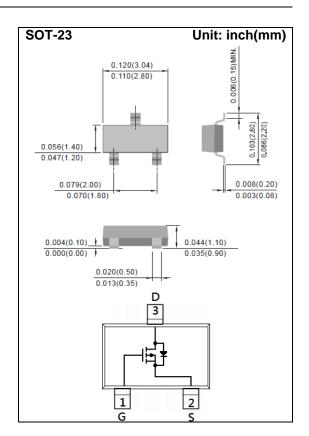
Voltage -30 V Current -2.9A

Features

- RDS(ON) , VGS@-10V, ID@-2.9A<110mΩ
- RDS(ON) , VGS@-4.5V, ID@-1.9A<150mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: A09



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-30	V
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V
Continuous Drain Current		I _D	-2.9	Α
Pulsed Drain Current		I _{DM}	-11.6	А
Power Dissipation	T _a =25°C	P _D	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-1	-1.31	-2.1	V		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-2.9A	-	92	110	mΩ		
		V _{GS} =-4.5V, I _D =-1.9A	-	120	150			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-0.01	-1	uA		
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA		
Dynamic								
Total Gate Charge	Q_g	V _{DS} =-15V, I _D =-2.9A, V _{GS} =-10V ^(Note 1,2)	-	9.8	-	nC		
Gate-Source Charge	Q_gs		-	1.5	-			
Gate-Drain Charge	Q_{gd}		-	2.2	-			
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V,	-	396	-	pF		
Output Capacitance	Coss		-	47	-			
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	36	-			
Switching								
Turn-On Delay Time	td _(on)	V_{DD} =-15V, I_{D} =-2.9A, V_{GS} =-10V, R_{G} =6 Ω (Note 1,2)	-	5	-			
Turn-On Rise Time	tr			30		ns		
Turn-Off Delay Time	td _(off)		-	25	-			
Turn-Off Fall Time	tf	R _G =012	-	8	-			
Drain-Source Diode								
Maximum Continuous Drain-Source				-	-1.5	А		
Diode Forward Current	I _S		-					
Diode Forward Voltage	V_{SD}	I _S =-1.0A, V _{GS} =0V		-0.77	-1.2	V		

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





TYPICAL CHARACTERISTIC CURVES

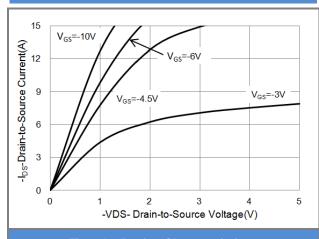


Fig.1 On-Region Characteristics

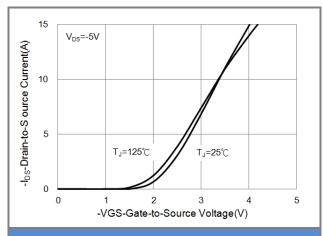


Fig.2 Transfer Characteristics

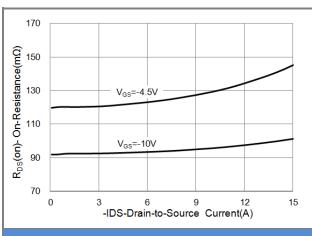


Fig.3 On-Resistance vs. Drain Current

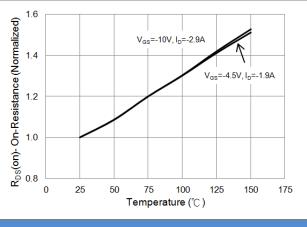
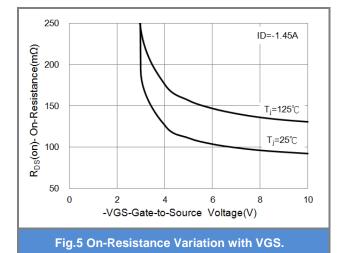


Fig.4 On-Resistance vs. Junction temperature



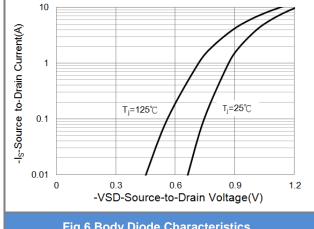


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

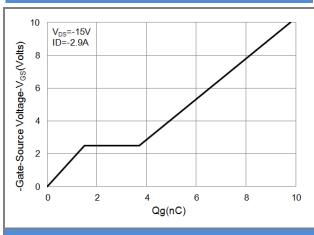


Fig.7 Gate-Charge Characteristics

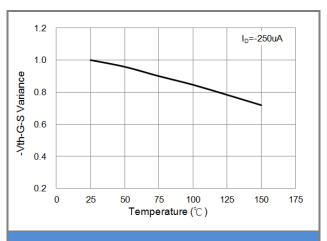


Fig.8 Threshold Voltage Variation with Temperature

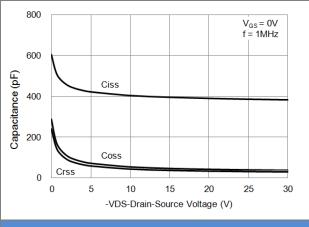


Fig.9 Capacitance vs. Drain-Source Voltage

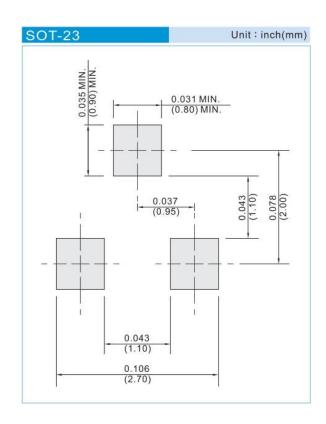




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJA3409_R1_00001	SOT-23	3K pcs / 7" reel	A09	Halogen free
PJA3409_R2_00001	SOT-23	12K pcs / 13" reel	A09	Halogen free

MOUNTING PAD LAYOUT







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